Dual D Flip-Flop with Set and Reset

High-Performance Silicon-Gate CMOS

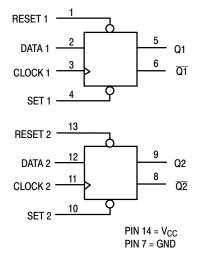
The MC74HC74A is identical in pinout to the LS74. The device inputs are compatible with standard CMOS outputs; with pullup resistors, they are compatible with LSTTL outputs.

This device consists of two D flip-flops with individual Set, Reset, and Clock inputs. Information at a D-input is transferred to the corresponding Q output on the next positive going edge of the clock input. Both Q and \overline{Q} outputs are available from each flip-flop. The Set and Reset inputs are asynchronous.

Features

- Output Drive Capability: 10 LSTTL Loads
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 2.0 to 6.0 V
- Low Input Current: 1.0 μA
- High Noise Immunity Characteristic of CMOS Devices
- In Compliance with the JEDEC Standard No. 7.0 A Requirements
- Chip Complexity: 128 FETs or 32 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

LOGIC DIAGRAM





ON Semiconductor®

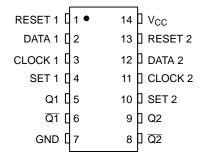
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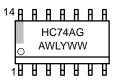


SOIC-14 NB D SUFFIX CASE 751A TSSOP-14 DT SUFFIX CASE 948G

PIN ASSIGNMENT



MARKING DIAGRAMS



SOIC-14 NB



TSSOP-14

A = Assembly Location

L, WL = Wafer Lot Y, YY = Year W, WW = Work Week G or = Pb-Free Package

(Note: Microdot may be in either location)

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

FUNCTION TABLE

| | Inputs | | | | puts |
|-----|----------------------|---------------|---|-------|-------|
| Set | Set Reset Clock Data | | | Ø | Q |
| L | Н | Χ | Χ | Н | L |
| Н | L | Χ | X | L | Н |
| L | L | Χ | X | H* | H* |
| Н | Н | \mathcal{L} | Н | Н | L |
| Н | Н | \mathcal{L} | L | L | Н |
| Н | Н | L | X | No CI | nange |
| Н | Н | Н | X | No CI | nange |
| Н | Н | ~ | Х | No CI | nange |

^{*}Both outputs will remain high as long as Set and Reset are low, but the output states are unpredictable if Set and Reset go high simultaneously.

MAXIMUM RATINGS

| Symbol | Parameter | Value | Unit |
|------------------|---|--------------------------|------|
| V _{CC} | DC Supply Voltage (Referenced to GND) | -0.5 to + 7.0 | V |
| V _{in} | DC Input Voltage (Referenced to GND) | -0.5 to V_{CC} + 0.5 | V |
| V _{out} | DC Output Voltage (Referenced to GND) | -0.5 to V_{CC} + 0.5 | V |
| I _{in} | DC Input Current, per Pin | ±20 | mA |
| l _{out} | DC Output Current, per Pin | ±25 | mA |
| I _{CC} | DC Supply Current, V _{CC} and GND Pins | ±50 | mA |
| P _D | Power Dissipation in Still Air, SOIC Package† | 500 | mW |
| | TSSOP Package† | 450 | |
| T _{stg} | Storage Temperature | -65 to +150 | °C |
| TL | Lead Temperature, 1 mm from Case for 10 Seconds | | °C |
| | (SOIC or TSSOP Package) | 260 | |
| | | 300 | |

This device contains protection circuitry to guard against damage due to high static voltages or electric fields. However, precautions must be taken to avoid applications of any voltage higher than maximum rated voltages to this high–impedance circuit. For proper operation, V_{in} and V_{out} should be constrained to the range GND \leq (V_{in} or V_{out}) \leq V_{CC} .

Unused inputs must always be tied to an appropriate logic voltage level (e.g., either GND or V_{CC}). Unused outputs must be left open.

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

†Derating: SOIC Package: -7 mW/°C from 65° to 125°C

TSSOP Package: -6.1 mW/°C from 65° to 125°C

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | | Max | Unit |
|------------------------------------|--|-----|-----------------|------|
| V _{CC} | DC Supply Voltage (Referenced to GND) | | 6.0 | V |
| V _{in} , V _{out} | DC Input Voltage, Output Voltage (Referenced to GND) | 0 | V _{CC} | V |
| T _A | Operating Temperature, All Package Types | -55 | +125 | °C |
| t _r , t _f | Input Rise and Fall Time $V_{CC} = 2.0 \text{ V}$ | 0 | 1000 | ns |
| | (Figures 1, 2, 3) $V_{CC} = 3.0 \text{ V}$ | 0 | 600 | |
| | $V_{CC} = 4.5 \text{ V}$ | 0 | 500 | |
| | $V_{CC} = 6.0 \text{ V}$ | 0 | 400 | |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

| | | | | Gu | Guaranteed Limit | | |
|-----------------|--|---|----------------------|----------------|------------------|-------------|------|
| Symbol | Parameter | Test Conditions | V _{CC} V | –55 to 25°C | ≤ 85 °C | ≤ 125°C | Unit |
| V _{IH} | Minimum High–Level Input | $V_{out} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$ | 2.0 3.0 | 1.5 2.1 | 1.5 | 1.5 | V |
| | Voltage | $ I_{out} \leq 20 \mu\text{A}$ | 3.0 4.5 | 3.15 | 2.1 3.15 | 2.1 3.15 | |
| | | | 6.0 | 4.2 | 4.2 | 4.2 | |
| V _{IL} | Maximum Low–Level Input | $V_{out} = 0.1 \text{ V or } V_{CC} - 0.1 \text{ V}$ | 2.0 3.0 | 0.5 0.9 | 0.5 | 0.5 | V |
| | Voltage | $ I_{out} \le 20 \mu\text{A}$ | 3.0 4.5 | 1.35 | 0.9 1.35 | 0.9 1.35 | |
| | | | 6.0 | 1.8 | 1.8 | 1.8 | |
| V _{OH} | Minimum High-Level Output | $V_{in} = V_{IH}$ or V_{IL} | 2.0 | 1.9 | 1.9 | 1.9 | V |
| | Voltage | $ I_{out} \le 20 \mu\text{A}$ | 4.5 | 4.4 | 4.4 | 4.4 | |
| | | | 6.0 | 5.9 | 5.9 | 5.9 | |
| | | $V_{in} = V_{IH} \text{ or } V_{IL} I_{out} \leq 2.4 \text{ mA}$ | 3.0 | 2.48 | 2.34 | 2.2 | |
| | | $ I_{out} \le 4.0 \text{ mA}$ | 4.5 | 3.98 | 3.84 | 3.7 | |
| | | $ I_{out} \le 5.2 \text{ mA}$ | 6.0 | 5.48 | 5.34 | 5.2 | |
| V_{OL} | Maximum Low-Level Output | $V_{in} = V_{IH}$ or V_{IL} | 2.0 | 0.1 | 0.1 | 0.1 | V |
| | Voltage | $ I_{out} \le 20 \mu\text{A}$ | 4.5 | 0.1 | 0.1 | 0.1 | |
| | | | 6.0 | 0.1 | 0.1 | 0.1 | |
| | | $V_{in} = V_{IH} \text{ or } V_{IL} I_{out} \leq 2.4 \text{ mA}$ | 3.0 | 0.26 | 0.33 | 0.4 | |
| | | $ I_{out} \le 4.0 \text{ mA}$ | 4.5 | 0.26 | 0.33 | 0.4 | |
| | | $ I_{out} \le 5.2 \text{ mA}$ | 6.0 | 0.26 | 0.33 | 0.4 | |
| l _{in} | Maximum Input Leakage Current | $V_{in} = V_{CC}$ or GND | 6.0 | ±0.1 | ±1.0 | ±1.0 | μΑ |
| Icc | Maximum Quiescent Supply Current (per Package) | $V_{in} = V_{CC}$ or GND $I_{out} = 0 \mu A$ | 6.0 | 2.0 | 20 | 80 | μΑ |

AC ELECTRICAL CHARACTERISTICS (C_L = 50 pF, Input t_r = t_f = 6.0 ns)

| | | | Gu | aranteed Li | mit | |
|--|---|--------------------------|-----------------------|-----------------------|------------------------|------|
| Symbol | Parameter | V _{CC} | – 55 to 25°C | ≤ 85°C | ≤ 125°C | Unit |
| f _{max} | Maximum Clock Frequency (50% Duty Cycle) (Figures 1 and 4) | 2.0 3.0 4.5 | 6.0 15 30 | 4.8 10 24 | 4.0 8.0 20 | MHz |
| | | 6.0 | 35 | 28 | 24 | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Clock to Q or Q (Figures 1 and 4) | 2.0 3.0 4.5 6.0 | 100 75 20 17 | 125 90 25 21 | 150 120 30 26 | ns |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Set or Reset to Q or Q (Figures 2 and 4) | 2.0 3.0 4.5 6.0 | 105 80 21 18 | 130 95 26 22 | 160 130 32 27 | ns |
| t _{TLH} , t _{THL} | Maximum Output Transition Time, Any Output (Figures 1 and 4) | 2.0 3.0 4.5 6.0 | 75 30 15 13 | 95 40 19 16 | 110 55 22 19 | ns |
| C _{in} | Maximum Input Capacitance | _ | 10 | 10 | 10 | pF |

| | | Typical @ 25°C, V _{CC} = 5.0 V | |
|----------|--|---|----|
| C_{PD} | Power Dissipation Capacitance (Per Flip-Flop)* | 32 | pF |

^{*} Used to determine the no–load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

TIMING REQUIREMENTS (Input $t_f = t_f = 6.0 \text{ ns}$)

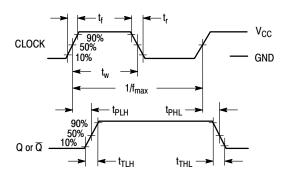
| | | | Gu | aranteed Li | mit | |
|---------------------------------|--|--------------------------|---------------------------|---------------------------|---------------------------|------|
| Symbol | Parameter | V _{CC} | –55 to 25°C | ≤ 85 °C | ≤ 125°C | Unit |
| t _{su} | Minimum Setup Time, Data to Clock (Figure 3) | 2.0 3.0 4.5 6.0 | 80 35 16 14 | 100 45 20 17 | 120 55 24 20 | ns |
| t _h | Minimum Hold Time, Clock to Data (Figure 3) | 2.0 3.0 4.5 6.0 | 3.0 3.0 3.0 3.0 | 3.0 3.0 3.0 3.0 | 3.0 3.0 3.0 3.0 | ns |
| t _{rec} | Minimum Recovery Time, Set or Reset Inactive to Clock (Figure 2) | 2.0 3.0 4.5 6.0 | 8.0 8.0 8.0 8.0 | 8.0 8.0 8.0 8.0 | 8.0 8.0 8.0 8.0 | ns |
| t _w | Minimum Pulse Width, Clock (Figure 1) | 2.0 3.0 4.5 6.0 | 60 25 12 10 | 75 30 15 13 | 90 40 18 15 | ns |
| t _w | Minimum Pulse Width, Set or Reset (Figure 2) | 2.0 3.0 4.5 6.0 | 60 25 12 10 | 75 30 15 13 | 90 40 18 15 | ns |
| t _r , t _f | Maximum Input Rise and Fall Times (Figures 1, 2, 3) | 2.0 3.0 4.5 6.0 | 1000 800 500 400 | 1000 800 500 400 | 1000 800 500 400 | ns |

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|------------------|-------------------------|-----------------------|
| MC74HC74ADG | SOIC-14 NB (Pb-Free) | 55 Units / Rail |
| NLV74HC74ADG* | SOIC-14 NB (Pb-Free) | 55 Units / Rail |
| MC74HC74ADR2G | SOIC-14 NB (Pb-Free) | 2500 / Tape & Reel |
| NLV74HC74ADR2G* | SOIC-14 NB (Pb-Free) | 2500 / Tape & Reel |
| MC74HC74ADTR2G | TSSOP-14 (Pb-Free) | 2500 / Tape & Reel |
| NLV74HC74ADTR2G* | TSSOP-14 (Pb-Free) | 2500 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.
*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.

SWITCHING WAVEFORMS

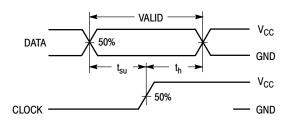


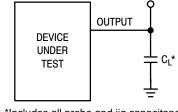
SET OR RESET $t_{\rm W}$ $V_{\rm CC}$ $V_{\rm CC}$

Figure 1.

Figure 2.

TEST POINT





*Includes all probe and jig capacitance

Figure 3.

Figure 4.

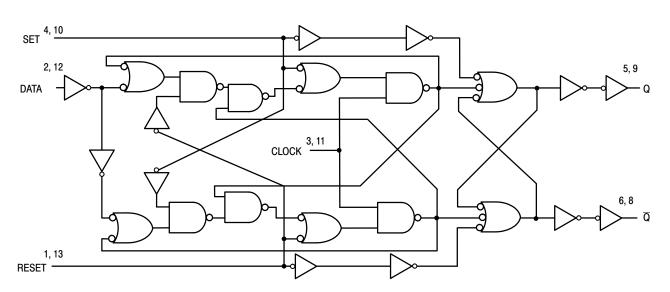


Figure 5. EXPANDED LOGIC DIAGRAM

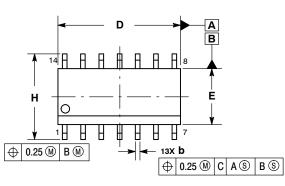


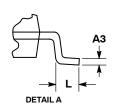


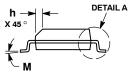
△ 0.10

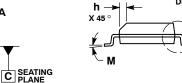
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DATE 03 FEB 2016





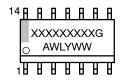




- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
 - ASME Y14.5M, 1994.
 CONTROLLING DIMENSION: MILLIMETERS.
- DIMENSION b DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF AT
- MAXIMUM MATERIAL CONDITION.
 DIMENSIONS D AND E DO NOT INCLUDE
 MOLD PROTRUSIONS.
- 5. MAXIMUM MOLD PROTRUSION 0.15 PER SIDE

| | MILLIMETERS | | INC | HES |
|-----|-------------|------|-----------|-------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 1.35 | 1.75 | 0.054 | 0.068 |
| A1 | 0.10 | 0.25 | 0.004 | 0.010 |
| АЗ | 0.19 | 0.25 | 0.008 | 0.010 |
| b | 0.35 | 0.49 | 0.014 | 0.019 |
| D | 8.55 | 8.75 | 0.337 | 0.344 |
| Е | 3.80 | 4.00 | 0.150 | 0.157 |
| е | 1.27 | BSC | 0.050 BSC | |
| Н | 5.80 | 6.20 | 0.228 | 0.244 |
| h | 0.25 | 0.50 | 0.010 | 0.019 |
| L | 0.40 | 1.25 | 0.016 | 0.049 |
| M | 0 ° | 7° | 0 ° | 7° |

GENERIC MARKING DIAGRAM*

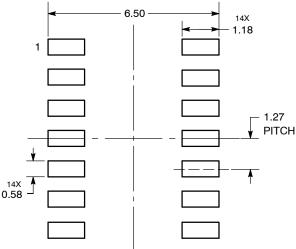


XXXXX = Specific Device Code Α = Assembly Location

WL = Wafer Lot Υ = Year WW = Work Week = Pb-Free Package

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.

SOLDERING FOOTPRINT*



DIMENSIONS: MILLIMETERS *For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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DATE 03 FEB 2016

| STYLE 1: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. NO CONNECTION 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. NO CONNECTION 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE | STYLE 2: CANCELLED | STYLE 3: PIN 1. NO CONNECTION 2. ANODE 3. ANODE 4. NO CONNECTION 5. ANODE 6. NO CONNECTION 7. ANODE 8. ANODE 9. ANODE 10. NO CONNECTION 11. ANODE 12. ANODE 13. NO CONNECTION 14. COMMON CATHODE | STYLE 4: PIN 1. NO CONNECTION 2. CATHODE 3. CATHODE 4. NO CONNECTION 5. CATHODE 6. NO CONNECTION 7. CATHODE 8. CATHODE 9. CATHODE 10. NO CONNECTION 11. CATHODE 12. CATHODE 13. NO CONNECTION 14. COMMON ANODE |
|---|---|---|---|
| STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE | STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE | STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 7. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE | STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 8. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE |

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